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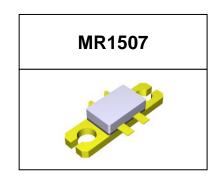
70W, 28V High Power RF LDMOS FETs

Description

The MR1507 is a 70-watt, unmatched, push pull LDMOS FETs, designed for Wide-band and Mobile radio applications with frequencies under 1500MHz. It can be used in Class AB/B and Class C for all typical modulation formats.

• Typical Performance (On Innogration fixture with device soldered): $V_{DD} = 28 \text{ Volts}, I_{DQ} = 500 \text{ mA}, CW.$

Frequency	Gp (dB)	P _{-1dB} (W)	η _D @P ₋₁ (%)	
1000 MHz	20	70	60	



Features

- High Efficiency and Linear Gain Operations
- Integrated ESD Protection
- Excellent thermal stability, low HCI drift

- Large Positive and Negative Gate/Source Voltage Range for Improved Class C Operation
- Pb-free, RoHS-compliant

Suitable Applications

- 30-88MHz (Ground communication)
- 54-88MHz (TV VHF I)
- 88-108MHz (FM)
- 118 -140MHz (Avionics)

- 136-174MHz (Commercial ground communication)
- 160-230MHz (TV VHF III)
- 30-512MHz (Jammer, Ground/Air communication)
- 470-860MHz (TV UHF)

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
DrainSource Voltage	V _{DSS}	+95	Vdc
GateSource Voltage	V_{GS}	-10 to +10	Vdc
Operating Voltage	V_{DD}	+40	Vdc
Storage Temperature Range	Tstg	-65 to +150	°C
Case Operating Temperature	T _c	+150	°C
Operating Junction Temperature	T,	+225	°C

Table 2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Case	Do 10	0.7	0000
T _C = 85°C, T _J =200°C, DC test	RθJC	0.7	°C/W

Table 3. ESD Protection Characteristics

Test Methodology	Class		
Human Body Model (per JESD22A114)	Class 2		

Table 4. Electrical Characteristics ($T_A = 25$ °C unless otherwise noted)

Characteristic	Symbol	Min	Tvp	Max	Unit
Characterione	Cymbol		. , ,	IVIOA	0

DC Characteristics (per half section)

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Drain-Source Voltage V _{GS} =0, I _{DS} =1.0mA	$V_{(BR)DSS}$	90	95		V
Zero Gate Voltage Drain Leakage Current (V _{DS} = 28 V, V _{GS} = 0 V)	I _{DSS}			1	μА
GateSource Leakage Current (V _{GS} = 9 V, V _{DS} = 0 V)	I _{GSS}			1	μА
Gate Threshold Voltage $(V_{DS} = 28V, I_D = 600 \mu A)$	V _{GS} (th)		2.11		V
Common Source Input Capacitance $(V_{GS} = 0V, V_{DS} = 28 \ V, f = 1 \ MHz)$	C _{iss}		34.1		pF
Common Source Output Capacitance (V _{GS} = 0V, V _{DS} =28 V, f = 1 MHz)	Coss		11.2		pF
Common Source Feedback Capacitance (V _{GS} = 0V, V _{DS} =28 V, f = 1 MHz)	C _{RSS}		0.9		pF
Common Source Input Capacitance (V _{GS} = 0V, V _{DS} =40 V, f = 1 MHz)	C _{iss}		34.1		pF
Common Source Output Capacitance (V _{GS} = 0V, V _{DS} =40 V, f = 1 MHz)	Coss		9.7		pF
Common Source Feedback Capacitance (V _{GS} = 0V, V _{DS} =40 V, f = 1 MHz)	C _{RSS}		0.86		pF

Functional Tests (On Demo Test Fixture, 50 ohm system) V_{DD} = 28 Vdc, I_{DQ} = 500 mA, f = 1000 MHz, CW Signal Measurements.

Power Gain	Gp	20	dB
Drain Efficiency@P1dB	η _D	60	%
1 dB Compression Point	P _{-1dB}	70	W
Input Return Loss	IRL	-10	dB

 $\textbf{Load Mismatch (In Innogration Test Fixture, 50 ohm system):} \quad V_{DD} = 28 \text{ Vdc}, I_{DQ} = 500 \text{ mA}, f = 1000 \text{ MHz}$

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	VSWR 10:1 at 20W pulse CW Output Power	No Device Degradation

Package Outline

Flanged ceramic package; 2 mounting holes; 4 leads

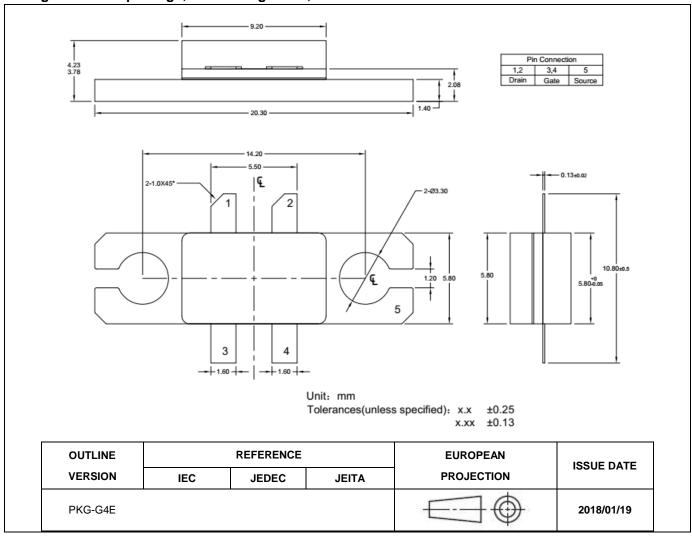


Figure 1. Package Outline PKG-G4E

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Revision history

Table 5. Document revision history

Date	Revision	Datasheet Status
2018/08/16	Rev 1.0	Product Datasheet
2018/8/21	Rev 1.1	Add capacitance info at 28V and 40V

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